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Experimental–Simulation Analysis of a Radiation Tolerant Erbium-Doped Fiber Amplifier for Space Applications

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Abstract: Research on optical amplifiers has highlighted how ionizing radiation negatively impacts the performance of erbium-doped fiber amplifiers (EDFAs), through the degradation of their gain. The amplitudes and kinetics of this degradation are mainly explained by the radiation-induced attenuation (RIA) phenomenon at the pump and signal wavelengths. In this work, the gain degradation of a radiation tolerant EDFA (exploiting a cerium-co-doped active optical fiber) induced by ionizing radiation up to 3 kGy (SiO₂), at two dose rates, 0.28 Gy/s and 0.093 Gy/s, is studied through an experimental/simulation approach. Using a home-made simulation code based on the rate and power propagation equations and including the RIA effects, the radiation-dependent performance of EDFAs were estimated. The variations in the spectroscopic parameters caused by irradiation were also characterized, but our results show that they give rise to EDFA gain degradation of about 1%. To overcome the issue of overestimating the RIA during the radiation tests on the sole active rare-earth-doped fiber, a new RIA experimental setup is introduced allowing us to better consider the photobleaching mechanisms related to the pumping at 980 nm. A good agreement between experimental and simulated gain degradation dose dependences was obtained for two different irradiation conditions, thus also validating the simulation code for harsh environments applications.

Keywords: optical fibers; erbium-doped fiber amplifier; ionizing radiations; simulation

1. Introduction

REDFs represent a key technology for the realization of amplifiers and lasers, with high gain, large bandwidth and good performance in terms of noise. Thanks to these characteristics, REDFs have proved to be an ideal solution in the field of telecommunications, specifically in the telecom window around 1550 nm [1]. Moreover, thanks to the small size, low weight and low power consumption of REDFs, they are recently finding great use in the context of space missions and satellite communications to ensure free space high-speed data transfer. REDFAs and REDFSs are used as part of space optical communications terminals to enable long-range communications as well as in fiber optic gyroscopes [2–8].

These devices are typically based on optical fibers doped with Er³⁺, Yb³⁺ ions or a combination of both. However, RE-based systems also have limitations in such harsh environments, linked to the effects of ionizing radiation (protons, electrons, etc.) present in space context, which give rise to the degradation of REDF performance; in fact, it has
been demonstrated that active fiber represents the most radiation-sensitive part of an EDFA [9,10].

The radiation effects on the optical fibers appear through three macroscopic phenomena. Among them, the main one is the RIA. It is an increase in the optical fiber losses that appear during irradiation. It is caused by the generation of point defects (color centers) in the host silica-based glass matrix, that lead to new absorption bands in the band gap. Generally, RIA increases with TID and then reduces partially after irradiation is stopped. The second effect is the RIE: it is constituted by Cerenkov light and radioluminescence light, that is, the light emission from pre-existing or radiation-induced centers, excited by the radiation. The last effect is the RIC, that takes place at high doses or at high neutron fluences [9,11,12].

The RIA directly affects the gain of the system. REDFs have been shown to be much more sensitive to radiation than telecom-grade germanosilicate optical fibers [13,14]. In fact, this vulnerability is not linked to the presence of RE ions, such as Er$^{3+}$ and Yb$^{3+}$ ions, but it is due to the presence of co-dopants, such as Al or P [8,15], added to the glass matrix to facilitate the incorporation of RE ions and to prevent the formation of RE ions clusters that limit the amplification efficiency [1,16].

Under steady-state radiation, for example, optical fibers can be classified into three groups, considering their RIA levels: sensitive, tolerant or resistant fibers. Examples of radiation-sensitive optical fibers include all fibers doped with P and/or Al in their core or cladding: their losses are so high that dosimeters are today based on such fibers. Among the radiation-tolerant optical fibers are the telecom-grade germanosilicate optical fibers, without P in their core and cladding, whereas radiation-hardened optical fibers are the ones with pure silica or F-doped cores and F-doped cladding, and N-doped optical fibers [9,17,18]. The sensitivity of REDFAs to ionizing radiation manifests itself mostly with a gain degradation. Over the years, various techniques have been developed at the component level to make REDFAs more radiation-resistant, including co-doping of the REDF core with cerium ions and/or pre-loading it with H$_2$ or D$_2$ [19–21]. The use of co-doping with cerium is justified by its ability, depending on its multivalent state, to trap electrons or holes that may be created during the radiation exposure and may have a significant contribution to the P- or Al-related defects generation [22,23].

During the last 30 years, the topic of point defects related to P and Al in the amorphous silica matrix, as well as in the active and passive optical fibers, has been investigated by researchers [24,25]. For example, EDFAs are usually co-doped with Al ions, but the exact natures of the Al-related point defects induced under radiation are not clear yet, especially in the infrared spectral region. However, it is known that the RIA in the infrared is influenced by the presence of the tail of the AlOHCs, whose absorption peaks around 540 nm, and by another defect, whose structure remains unknown. For the EDFAs, while the pump transmission at 980 nm is affected by the AlOHC presence, the signal at 1550 nm is mainly impacted by this unknown center [25].

Under specific conditions such as EDFAs (where a pump signal is injected into the guide), the PB begins to compete with the radiation-induced defect generation by enhancing the recombination of defects. By injecting a pump signal at the appropriate wavelength and power into the fiber, metastable defects created by radiation can recombine not only thermally but also thanks to the energy supplied by the injected light. Then, PB allows us to reduce the RIA by accelerating its recovery processes [25,26]. In the case of EDFA, the injected signal able to induce a PB phenomenon is the pump signal at 980 nm [27]. In a previous study, Aubry et al. [28] noted that by injecting the high-power pump signal into an EDF with a core co-doped with cerium during the 80% of the irradiation run time duration, the RIA at 980 nm is reduced by 20%, while the RIA at 1550 nm is reduced by 50%, compared to the case in which the pump signal is not injected into the fiber. Moreover, radiations can also influence the spectroscopic parameters of the fiber, as reported in [29–32].

This work aims to analyze, through an experimental–simulation approach, the gain degradation induced by the presence of ionizing radiations in the space environment.
Generally, for space applications in which EDFAs are used, the TID of kGy can be reached for the most challenging mission, so in this study, we will consider a maximum dose of 3 kGy (SiO$_2$) that covers rather the current and future space needs.

Since an EDFA using a Ce co-doped fiber presents a better radiation resistance than one based on telecom-grade active fiber, without Ce-doping or H$_2$ loading [20,23], we will focus our study on such an EDFA. The gain degradation will be measured experimentally and evaluated using a simulation code based on the PSO algorithm [33,34] which solves the rate equations of the involved energy levels and the power propagation equations. The radiation effects giving RIA and changing the spectroscopic parameters as radiative lifetime, emission and absorption cross sections were considered in the numerical code, too. This work highlights a good agreement between the measured and simulated gain degradation kinetics and allows us to understand the basic mechanisms that rule the gain degradation.

2. Simulation and Experimental Procedure

2.1. Tested Optical Fiber and Amplifier

The FUT was an aluminosilicate fiber co-doped with erbium and cerium, manufactured by EXAIL (Lannion, France). The diameter of the fiber core and cladding are 2.8 µm/127 µm, respectively. Additional optical fiber details are given in Table 1.

Table 1. Optical fiber parameters.

<table>
<thead>
<tr>
<th>Core/Cladding Diameter</th>
<th>Erbium Ions Concentration</th>
<th>Losses @1530 nm</th>
<th>Losses @980 nm</th>
<th>Background Losses</th>
<th>Core Dopants</th>
</tr>
</thead>
<tbody>
<tr>
<td>2.8 µm/127 µm</td>
<td>$1.21 \times 10^{19}$ ions/cm$^3$</td>
<td>24 dB/m</td>
<td>14 dB/m</td>
<td>6.2 dB/km</td>
<td>Al-Er-Ce</td>
</tr>
</tbody>
</table>

Table 2 summarizes the details related to the EDFA used in the experiments, specifying the operational and physical conditions.

Table 2. EDFA parameters.

<table>
<thead>
<tr>
<th>Fiber Length</th>
<th>Signal–Pump Configuration</th>
<th>Signal Power at 1550 nm</th>
<th>Pump Power at 980 nm</th>
</tr>
</thead>
<tbody>
<tr>
<td>4.3 m</td>
<td>Co-propagating</td>
<td>1 µW</td>
<td>50 mW</td>
</tr>
</tbody>
</table>

The optimized length of 4.3 m was obtained experimentally and through the simulation code, and it corresponds to a maximum gain equal to 31.8 dB [35].

2.2. Theoretical Model

The theoretical model is based on the differential equations underlying the multilevel rate equations describing the ion populations of the different erbium energy levels, as well as the power propagation equations describing the longitudinal evolution of pump, signal and amplified spontaneous emission (ASE) power. A schematic of the Er$^{3+}$ energy level system illustrating the transitions considered in the model is shown in Figure 1.

Specifically, in our simulations, the following phenomena were taken into account: (1) spontaneous decay from $^4$I$_{13/2}$, $^4$I$_{11/2}$ and $^4$I$_{9/2}$ energy levels; (2) pump absorption and stimulated emission between $^4$I$_{15/2}$ and $^4$I$_{11/2}$ energy levels; (3) signal absorption and stimulated emission between $^4$I$_{15/2}$ and $^4$I$_{13/2}$ energy levels; (4) uniform cooperative upconversion between a pair of excited Er$^{3+}$ ions: $^4$I$_{13/2}$ + $^4$I$_{13/2}$ → $^4$I$_{15/2}$ + $^4$I$_{15/2}$ and $^4$I$_{11/2}$ + $^4$I$_{11/2}$ → $^4$I$_{15/2}$ + $^4$S$_{3/2}$; (5) cross-relaxation process between two Er$^{3+}$ ions: $^4$I$_{9/2}$ + $^4$I$_{15/2}$ → $^4$I$_{13/2}$. The rate Equations (1)–(5) are reported below and are solved with the simulation code using the Newton–Raphson method:

$$\frac{dN_1}{dt} = -(W_{12} + W_{13})N_1 + W_{31}N_3 + W_{21}N_2 + N_2 N_4 + C_{up}N_2^2 + C_3N_3^2 - C_{14}N_1N_4$$ (1)
\[
\frac{dN_2}{dt} = W_{12}N_1 - W_{21}N_2 - \frac{N_2}{\tau_{21}} - 2C_{up}N_2^2 + C_{14}N_1N_4
\]  
(2)

\[
\frac{dN_3}{dt} = W_{13}N_1 - W_{31}N_3 + A_{43}N_4 - A_{32}N_3 - C_3N_3^2
\]  
(3)

\[
\frac{dN_4}{dt} = -A_{43}N_4 + A_{32}N_3 + C_{up}N_2^2 - C_{14}N_1N_4
\]  
(4)

\[
\sum_{i=1}^{4} N_i = N_{Er}
\]  
(5)

\[
\frac{dP_{p}^{\pm}(z)}{dz} = \pm \Gamma(v_p)[N_3\sigma_e(v_p) - N_4\sigma_a(v_p) - \alpha(v_p)]P_{p}^{\pm}(z)
\]  
(6)

\[
\frac{dP_{s}^{\pm}(z)}{dz} = \pm \Gamma(v_s)[N_2\sigma_e(v_p) - N_1\sigma_a(v_p) - \alpha(v_p)]P_{s}^{\pm}(z)
\]  
(7)

\[
\frac{dP_{ASE}^{\pm}(z,v_k)}{dz} = \pm \Gamma(v_k)[N_2\sigma_e(v_k) - N_1\sigma_a(v_k) - \alpha(v_k)]P_{ASE}^{\pm}(z,v_k) \pm 2N_2\Gamma(v_k)h\nu_k\Delta\nu_k\sigma_e(v_k)
\]  
(8)

In (6)–(8), \(v_p\) and \(v_s\) correspond to the frequency of the pump and signal, respectively; \(\sigma_e\) and \(\sigma_a\) are the emission and absorption cross sections of \(\text{Er}^{3+}\) ions, respectively; and \(\alpha\) is the total attenuation of active fiber, which also includes RIA. The forward and backward components of ASE noise spread over a continuous frequency range. Thus, in order to perform the numerical computations, the whole \(\text{Er}^{3+}\) spectrum is sampled into \(K\) frequency slots centered at the frequency \(v_k\) with bandwidth \(\Delta\nu_k\), \(k = 1, 2, \ldots, K\). The overlap factor \(\Gamma(v)\)
quantifying the transverse optical mode profile overlapping with erbium ion distribution is defined as follows

\[
\Gamma(\nu) = \frac{\int_{0}^{2\pi} \int_{0}^{R_c} |E(r, \phi, \nu)|^2 r dr d\phi}{\int_{0}^{2\pi} \int_{0}^{\infty} |E(r, \phi, \nu)|^2 r dr d\phi}
\]

(9)

with

\[
\int_{0}^{2\pi} \int_{0}^{\infty} |E(r, \phi, \nu)|^2 r dr d\phi = 1
\]

(10)

In (9), we consider that the actual erbium ion distribution is constant on the optical fiber core with radius \( R_c \). Moreover, \( E(r, \phi, \nu) \) is the transverse electric field envelope normalized using Equation (10). The overlap factor is a very important parameter, since it quantifies the percentage of the guided optical mode that interacts with the RE doping the fiber core. Therefore, an accurate calculation of the overlap factor results in an accurate estimate of the REDFA performance [33].

The computational code used for the prediction of the EDFA performance needs various input parameters: fiber parameters (fiber length, core radius, overlapping factor); spectroscopic parameters (radiative and non-radiative lifetimes, upconversion and cross-relaxation coefficients, erbium ion concentration, emission and absorption cross sections spectra); operative parameters (pump and signal wavelengths, pump and signal power, pumping scheme) and irradiation parameters (RIA at pump and signal wavelengths, which depend on dose rate, dose and temperature).

2.3. Spectroscopic Characterization

Among the used values of the spectroscopic parameters, some have been measured experimentally on the FUT, while others have been taken from the literature. Table 3 reports the values used in the simulation code.

**Table 3.** List of spectroscopic parameters and their corresponding values used in the simulation code. □ refers to the parameters measured experimentally.

<table>
<thead>
<tr>
<th>Spectroscopic Parameter</th>
<th>Value</th>
</tr>
</thead>
<tbody>
<tr>
<td>( J_{13/2} ) Lifetime ( \tau_{21} )</td>
<td>8.72 ms (□)</td>
</tr>
<tr>
<td>( J_{11/2} ) Lifetime ( \tau_{32} )</td>
<td>10 ( \mu s ) [23]</td>
</tr>
<tr>
<td>( J_{9/2} ) Lifetime ( \tau_{43} )</td>
<td>0.1 ( \mu s ) [23]</td>
</tr>
<tr>
<td>( \sigma_1 ) Er(^{3+}) @1530 nm</td>
<td>( 8.8 \times 10^{-25} ) ( m^2 ) (□)</td>
</tr>
<tr>
<td>( \sigma_1 ) Er(^{3+}) @1530 nm</td>
<td>( 9.3 \times 10^{-25} ) ( m^2 ) (□)</td>
</tr>
<tr>
<td>( \sigma_1 ) Er(^{3+}) @980 nm</td>
<td>( 6 \times 10^{-25} ) ( m^2 ) (□)</td>
</tr>
<tr>
<td>( \sigma_3 ) Er(^{3+}) @980 nm</td>
<td>( 0.007 \times 10^{-25} ) ( m^2 ) (□)</td>
</tr>
<tr>
<td>( C_{up} )</td>
<td>( 4 \times 10^{-24} ) ( m^3/s ) [23]</td>
</tr>
<tr>
<td>( C_3 )</td>
<td>( 1.09 \times 10^{-24} ) ( m^3/s ) [23]</td>
</tr>
<tr>
<td>( C_{14} )</td>
<td>( 6.4 \times 10^{-23} ) ( m^3/s ) [23]</td>
</tr>
</tbody>
</table>

The Er\(^{3+}\) absorption cross section was calculated from the absorption spectrum of the tested EDF, obtained through the cutback technique [38,39] and using the following formula:

\[
\sigma_{a}^{Er}(\nu) = \frac{at^{Er}(\nu)}{10 \log(e) N_{Er} \Gamma(\nu)}
\]

(11)

where \( N_{Er} \) is the Er\(^{3+}\) ion concentration, reported in Table 2. On the basis of the McCumber theory, the Er\(^{3+}\) emission cross section was calculated by the relationship

\[
\sigma_{e}^{Er}(\nu) = \sigma_{a}^{Er}(\nu) e^{\frac{E}{kT}}
\]

(12)

where \( E \) is the energy difference between the lower lying state of the multiplet forming the \( J_{13/2} \) energy level and lower lying state of the multiplet forming the ground state \( J_{15/2} \); \( T \) is the temperature; and \( k \) and \( h \) are the Boltzmann and Planck constants, respectively.
The lifetime measurements were performed using the TRL technique. The set-up description was reported in Ladaci et al. [29,40]. The radiation-induced variations in the Er$^{3+}$ absorption and emission cross sections and the lifetime of the $^4I_{13/2}$ energy level were also measured, to evaluate their influence on the gain degradation.

2.4. RIA Measurements

In order to evaluate the performances of EDFA under the ionizing radiation, the simulation code needs to know how the transmissions at the pump and signal wavelengths are degraded under radiation, so RIA measurements were also carried out. To evaluate the evolution of RIA as a function of the absorbed dose, the EDF, introduced in Section 2.1, was irradiated in the MOPERIX facility of the Laboratoire Hubert Curien (Saint-Etienne, France). This is characterized by a Tungsten tube operating with a 100 kV voltage, that gives a mean energy fluence of 40 keV.

In the previous work of our research group, Aubry et al. [28] showed that adding periods of high pump power during the fiber testing reduces the measured RIA at the pump and signal wavelengths. They used an experimental setup for the RIA measurements that allowed them to inject, considering time slots of 15 min, the pump signal into the FUT during the 80% of the time, while during the remaining 20%, only a low-power light source was injected to allow the RIA spectral acquisition. The percentage of time in which the pump signal is not injected into the fiber can cause an overestimation of the RIA obtained during the operation of an EDFA. Indeed, during the fiber testing, there is a lower contribution of the PB to the RIA reduction. This RIA overestimation was potentially identified as one of the causes of the slight observed disagreement between measured and simulated gain degradation kinetics on a similar EDFA, observed at high TIDs in a previous work [28]. For this reason, in this work, we developed a new experimental setup for RIA measurements, that was able to reduce the percentage of time during which the pump is not injected into the fiber.

Figure 2 reports the experimental setup used for the RIA measurement. The signals of two sources, the 1999CHP pump diode at 980 nm by 3S Photonics (Nozay, France) and a halogen white light source from Ocean Optics (Orlando, FL, USA), were injected through an optical switch (belonging to the Thorlabs PRO8000-4 rack) into the EDF. The white light signal was then collected, thanks to another switch synchronized to the first one, with an IR spectrometer (the NIRQuest spectrometer by Ocean Optics), while the pump was recorded using the YOKOGAWA Optical Spectrum Analyzer (OSA) (Tokyo, Japan). The considered EDF sample had a length of 19 cm.

The two-switch system allows one signal to pass through the EDF at a time. Using this type of system, we can adjust the percentage of time the pump signal is injected into the EDF through a LabVIEW 2015 program. Obviously, the pump signal cannot be injected 100% of the time into the EDF, as we need the white light signal to determine the impact of ionizing radiation on the fiber transmission. However, we can obtain very high percentages of time in which the pump signal is injected into the EDF, such as 99%.
In this work, two different dose rates were investigated: 0.28 Gy/s (SiO$_2$) and 0.093 Gy/s (SiO$_2$) up to a TID of 3 kGy. Moreover, at each dose rate, two irradiation runs were carried out, employing different percentages of time in which the pump was injected into the EDF, as highlighted in Table 4. The pump power used in these measurements was 50 mW, the same used for gain degradation measurements. This kind of measurement was carried out at a temperature of 25 °C.

Table 4. Specifications of the RIA measurements performed.

<table>
<thead>
<tr>
<th>RIA Measurement</th>
<th>Dose Rate</th>
<th>Percentage of Pump Time</th>
<th>Percentage of No Pump Time</th>
</tr>
</thead>
<tbody>
<tr>
<td>#1</td>
<td>0.28 Gy/s (SiO$_2$)</td>
<td>85%</td>
<td>15%</td>
</tr>
<tr>
<td>#2</td>
<td>0.28 Gy/s (SiO$_2$)</td>
<td>97%</td>
<td>3%</td>
</tr>
<tr>
<td>#3</td>
<td>0.093 Gy/s (SiO$_2$)</td>
<td>97%</td>
<td>3%</td>
</tr>
<tr>
<td>#4</td>
<td>0.093 Gy/s (SiO$_2$)</td>
<td>99%</td>
<td>1%</td>
</tr>
</tbody>
</table>

2.5. Gain Degradation Measurements

In order to evaluate the gain degradation under irradiation, the EDFA was also irradiated with the same X-ray machine and irradiation conditions. The setup used for the gain measurement, reported in Figure 3, is as follows: 1999CHP pump diode at 980 nm by 3S Photonics, a 1550 nm laser diode with an isolator and a WDM combiner from IDIL Fibres Optiques (Lannion, France).

The amplified signal is acquired by the YOKOGAWA OSA. For the measurements, a 4.3 m-long EDF was used, since this length allows the maximum gain to be achieved with a 50 mW pump at 980 nm and a 1 µW signal at 1550 nm. Also, in this case, the temperature of the experiment is 25 °C.

3. Results

3.1. $^{4}I_{13/2}$ Energy Level Lifetime

Using the TRL technique [29,40], it was possible to determine the evolution of the lifetime of the $^{4}I_{13/2}$ energy level as a function of different accumulated doses on different various EDF samples. Figure 4 shows that the $^{4}I_{13/2}$ energy level lifetime does not depend on the absorbed dose within ~3%.

The average measured lifetime, introduced in the simulation code, was 8.72 ms and it agrees with the result reported in [29] for an Er$^{3+}$/Yb$^{3+}$ co-doped fiber. This independence from the dose, at least up to 3 kGy, is associated with the presence of Ce$^{3+}$ ions within the silica glass matrix. In general, the $^{4}I_{13/2}$ energy level lifetime of Er$^{3+}$ for Ce$^{3+}$-undoped EDF should decrease with an increasing dose because of the changes in the host glass matrix environment induced by ionizing radiation [29]. The presence of Ce$^{3+}$ ions makes the EDF more radiation-hardened, reducing the changes induced by the radiations on the environment of the silica matrix and then keeping the lifetime constant. A sort of compromise is found regarding the introduction of Ce$^{3+}$ ions in the EDF: there is a robustness of the...
The radiation-induced gain degradation must then be mainly due to a TID of 3 kGy. 
The amplified signal is acquired by the YOKOGAWA OSA. For the measurements, a 50 mW pump at 980 nm and a 1 µW signal at 1550 nm. Also, in this case, the temperature was fixed at 20°C, and the temperature rise of the EDF was monitored. The temperature increase was calculated as the difference between the temperature of the EDF and the temperature of the YOKOGAWA OSA.

As a consequence, the radiation slightly affects the spectroscopic parameters, up to a TID of 3 kGy, with an absorbed dose of 3 kGy.

$^{4}I_{13/2}$ lifetime with respect to ionizing radiation, at the expense of a small reduction in the lifetime, from 10 ms [31] for an aluminosilicate fiber without Ce$^{3+}$ to 8.72 ms for our EDF.

Figure 4. $^{4}I_{13/2}$ energy level lifetime as a function of the dose.

3.2. Absorption and Emission Cross Sections

Figure 5a shows the absorption spectrum, obtained through the cutback technique [38,39], of two EDF samples, one pristine and the other pre-irradiated at 3 kGy (dose rate of 0.28 Gy/s, without injecting any signal into the fiber, therefore without considering the PB effect. It must be noted that there is only a slight increase in fiber losses, compared to the pristine losses, with an absorbed dose of 3 kGy.

Figure 5b shows the absorption and emission cross sections, both in pristine and irradiated samples, obtained using the mathematical formula presented in Section 2.3. The increase in fiber losses leads to an increase in the absorption and emission cross sections, of $0.5 \times 10^{-25}$ m$^2$ at 1530 nm, at a TID of 3 kGy.

Through the simulation code, it has been obtained that the gain variation in an EDFA associated with these small changes in the absorption and emission cross sections is less than 1%. As a consequence, the radiation slightly affects the spectroscopic parameters, up to a TID of 3 kGy. The radiation-induced gain degradation must then be due mainly to the RIA phenomenon.
Therefore, in the code simulations, whose results will be reported in the next section, the cross sections were considered constant. The absorption and emission cross sections at 980 nm and 1550 nm values used in the simulations have been reported in Table 2.

3.3. RIA Measurements Results

The main parameter that affects the gain under radiation is the RIA. But, because of the PB effect induced by the high pump power, the RIA must be measured in conditions as close as possible to the ones of an EDFA. The focal point of this work is to measure the RIA while injecting the pump with the highest percentage possible, in order not to overestimate the RIA level, and then to compare the measured behavior of EDFA under irradiation with the simulated one. The RIA was monitored up to a maximum dose of 3 kGy and during the post-irradiation recovery phase, which lasts 2 h for the dose rate of 0.28 Gy/s and 6 h for 0.093 Gy/s.

Figure 6 shows the spectral RIA obtained at the maximum dose for the four different irradiation conditions, whose specifications are listed in Table 4. The obtained RIAs agree with those reported in [25,28] and are mainly due to the tail of the Al-OHC point defects, whose absorption band is centered in the visible range around 540 nm, and to a not-yet-well-known defect absorbing in the IR [25]. Thus, whereas at 980 nm, the RIA is associated with the presence of the Al-OHCs, at 1550 nm, on the other hand, the RIA is linked to the unknown center. For both dose rates, it can be noted that the RIA is lower as the percentage of time the pump signal was injected into the EDF increases: the higher the percentage of time the pump signal was injected into the fiber, the greater the impact of the PB and the lower the RIA.

![Spectral RIA at 3 kGy TID](image)

**Figure 6.** Spectral RIA obtained at 3 kGy TID for the four different case studies.

Furthermore, it can be observed that for the same pump percentage for both dose rates (97%), the RIA is lower for the lower dose rate, as already observed for this EDF but also for other fibers. This is due to the fact that with a lower dose rate the defects have more time to recombine during the irradiation run [41,42].

Figure 7a,b show the RIA as a function of the absorbed dose, at the pump and signal wavelengths, respectively.

The RIA values at 980 nm and 1550 nm, reported in Figure 7a,b, were averaged over a 4 nm wide range around the wavelength of interest, obtaining a relative error of the RIA less than 3%.
Figure 6. Spectral RIA obtained at 3 kGy TID for the four different case studies.

Figure 7a,b show the RIA as a function of the absorbed dose, at the pump and signal wavelengths, respectively.

(a) (b)

Figure 7. Dose dependence of the (a) 980 nm RIA (b) 1550 nm RIA for various 980 nm pumping conditions.

At both wavelengths, the RIA increases almost linearly with the dose, as expected for aluminosilicate matrix. As already observed in Figure 6, by increasing the pump percentage, and getting closer and closer to the EDFA real application case, the RIA amplitude is reduced. Moreover, a lower dose rate corresponds to a lower RIA. It is interesting to note that, in Figure 7a, during the recovery phase, the RIA at 980 nm decreases slightly, with a recovery rate of 10%, whereas the RIA at 1550 nm (Figure 7b) shows a slight recovery only at the highest investigated dose rate and with the lower percentage of time using the pump. For the other irradiation runs (#2, #3 and #4), no recovery is observed at 1550 nm. This may be explained as follows: the not-well-known defect that characterizes the RIA at 1550 nm and that is generated under these irradiation conditions, is created at lower concentration but it appears also to be more stable.

It is worth noticing that the RIA values employed in the calculation code were measured on a 19 cm-long sample, while the optimal active fiber length for the EDFA is 4.3 m. The impact of PB varies as a function of the sample length, which means that it should not be uniform. However, the RIA measurement cannot be carried out on a sample of the same length as the fiber used for the gain degradation measurements, which is 4.3 m, as the losses of the pristine fiber result in being too high [28]. We can only make the hypothesis that the measured RIA is a good approximation of the real situation.

3.4. Gain Degradation Measurements Results

The gain degradation measurements were performed through the measurement setup introduced in Section 2.5 and are reported for the two dose rates in Figure 8.

First, a lower gain degradation was observed at a lower dose rate, in agreement with the lower measured RIA [41,42].

Furthermore, for both dose rates, the evolution of the gain degradation with dose has an almost linear trend, in line with the linear trend of the RIA at 980 nm and 1550 nm shown in Figure 7a,b. The error bars associated with the gain degradation in Figure 8 consider the error related to the peak and noise determination of the amplified and injected signals at 1550 nm, which is equal to ~3% of the gain.
both wavelengths of interest increases faster with the dose than in the 97% pump injection case. The deviation between the experimental and simulated curves increases with the dose, since the RIA at both 0.093 Gy/s and 0.28 Gy/s dose rates, with the simulated one that considered the measured RIA, trying to obtain the best fit. The second goal was to compare the measured gain degradation, at two dose rates.

4. Discussion

The simulation code, validated in [33–36], is able to predict the behavior of an EDFA under ionizing radiation, when introducing the measured RIA values into the simulation code itself. Then, the simulated estimate of the gain degradation can be compared with the measured ones, as presented in Figure 9a,b, for the dose rate 0.28 Gy/s and 0.093 Gy/s, respectively.

For the highest dose rate, in Figure 9a, it can be highlighted that the simulated curve that best adheres to the experimental one is the one that considers the RIA values obtained with the highest pump time percentage (97% of the time slot). Therefore, we can denote that the higher the pump time percentage is, the smaller the deviation between the simulated and experimental curves and the better the software prediction will be. We have a maximum error of 20% in the case of the 85% injected pump. In this case, the deviation between the experimental and simulated curves increases with the dose, since the RIA at both

![Figure 8. Gain degradation as a function of the dose, for two dose rates: 0.28 Gy/s (blue dots) and 0.0093 Gy/s (red dots), at 25 °C.](image)

![Figure 9. Evolution of measured–simulated gain degradation as the dose varies, for two dose rates: (a) 0.28 Gy/s; (b) 0.093 Gy/s.](image)
wavelengths of interest increases faster with the dose than in the 97% pump injection configuration in Figure 7.

In conclusion, a larger time percentage of the pump injection implies a smaller overestimation of the RIA and a result closer to the one occurring in the EDFA.

Figure 9b compares the experimental curve at a dose rate of 0.093 Gy/s and the simulated ones with a pump percentage of 97 and 99%. Both simulated curves agree with the measured one, within their error bars; however, by increasing the pump injection from 97 to 99%, the agreement slightly improves. In the closest possible situation to the real one, that of the blue curve in Figure 9b obtained by injecting the pump 99% of the time, the EDFA performance can be predicted with an error of less than 2%, since the overestimation of the RIA is strongly minimized. For the case of the red curve, with a pump injection of 97%, there is a maximum error of 5%, found at the maximum dose absorbed by the EDFA, which is 3 kGy. However, a pump percentage of 99% cannot be applied for each dose rate, because in cases of very high dose rates, in which the time slot is short, there might not be the possibility of recording a minimum number of acquisitions.

We probably have a pump signal that remains in the 4.3 m of fiber sufficient to have a positive effect of the PB linked to the pump on the RIA.

5. Conclusions

In this work, an analysis of the performance of an EDFA in a harsh environment, subjected to the presence of ionizing radiation, was carried out. From the literature [22–25], the modification and worsening of the behavior of optical amplifiers under the effect of radiation was known. Our first objective was to understand what were the factors impacting on the degradation of the performance of the amplifiers, including the spectroscopic parameters and the RIA, and quantify their impact on the amplifier gain. It was observed that, for the sample studied, the variation in the spectroscopic parameters has an impact of less than 1% on the gain of the EDFA, and therefore, it was concluded that the RIA is the main factor that degrades the EDFA gain.

The second goal was to compare the measured gain degradation, at two different dose rates, with the simulated one that considered the measured RIA, trying to obtain the best possible agreement between experiment and simulation.

Specifically, for the simulation of the gain degradation relating to an RIA measurement at a dose rate of 0.093 Gy/s and a pump injected for 99% of the time slot, an almost perfect agreement was obtained between the experimental and the simulated curves with a maximum error of 2%.

In conclusion, the software, combined with this RIA measurement setup, presented in Section 2.4, turns out to be a good solution for predicting the behavior of an optical amplifier subjected to the effect of ionizing radiation.


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Abbreviations

The following abbreviations are used in this manuscript:

- AlOHC - Al-oxygen hole center
- ASE - Amplified spontaneous emission
- EDF - Erbium-doped fiber
- EDFA - Erbium-doped fiber amplifier
- FUT - Fiber under test
- PB - Photobleaching
- PSO - Particle swarm optimization
- RE - Rare earth
- REDF - Rare-earth-doped fiber
- REDFA - Rare-earth-doped fiber amplifier
- REDFS - Rare-earth-doped fiber source
- RIA - Radiation-induced attenuation
- RIE - Radiation-induced emission
- RIC - Radiation-induced compaction
- TID - Total ionizing dose
- TRL - Time-resolved luminescence
- WDM - Wavelength division multiplexing

References


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